

2N3823, 2N3824**N-Channel Silicon Junction Field-Effect Transistor**

- VHF Amplifiers
- Small Signal Amplifiers

Absolute maximum ratings at $T_A = 25^\circ\text{C}$

Reverse Gate Source & Reverse Gate Drain Voltage	- 50 V
Continuous Forward Gate Current	10 mA
Continuous Device Power Dissipation	300 mW
Power Derating	2 mW/ $^\circ\text{C}$

At 25°C free air temperature:

		2N3823		2N3824		Process NJ32	
		Min	Max	Min	Max	Unit	Test Conditions
Gate Source Breakdown Voltage	$V_{(\text{BR})\text{GSS}}$	- 30		- 50		V	$I_G = - 1 \mu\text{A}, V_{\text{DS}} = \emptyset\text{V}$
Gate Reverse Current	I_{GSS}		- 0.5		- 0.1	nA	$V_{\text{GS}} = - 30\text{V}, V_{\text{DS}} = \emptyset\text{V}$
			- 0.5		- 0.1	μA	$V_{\text{GS}} = - 30\text{V}, V_{\text{DS}} = \emptyset\text{V}$
Gate Source Voltage	V_{GS}	- 1	- 7.5			V	$V_{\text{DS}} = 15\text{V}, I_D = 400 \mu\text{A}$
Gate Source Cutoff Voltage	$V_{\text{GS}(\text{OFF})}$		- 8			V	$V_{\text{DS}} = 15\text{V}, I_D = 0.5 \text{nA}$
Drain Saturation Current (Pulsed)	I_{DSS}	4	20			mA	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = \emptyset\text{V}$
Drain Cutoff Current	$I_{\text{D}(\text{OFF})}$			0.1	nA	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = - 8\text{V}$	
				0.1	μA	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = - 8\text{V}$	$T_A = 150^\circ\text{C}$

Dynamic Electrical Characteristics

Drain Source ON Resistance	$r_{\text{ds}(\text{on})}$				250	Ω	$V_{\text{GS}} = \emptyset\text{V}, I_D = \emptyset\text{V}$	$f = 1 \text{ kHz}$
Common Source Forward Transconductance	g_{fs}	3500	6500			μS	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = \emptyset\text{V}$	$f = 1 \text{ kHz}$
Common Source Forward Transmittance	$ Y_{\text{fs}} $	3200				μS	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = \emptyset\text{V}$	$f = 100 \text{ MHz}$
Common Source Output Conductance	g_{os}		35			μS	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = \emptyset\text{V}$	$f = 1 \text{ kHz}$
Common Source Input Capacitance	C_{iss}		6		6	pF	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = \emptyset\text{V}$	$f = 1 \text{ MHz}$
Common Source Reverse Transfer Capacitance	C_{rss}		2		3	pF	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = \emptyset\text{V}$	$f = 1 \text{ MHz}$
Equivalent Short Circuit Input Noise Voltage	\bar{e}_N		200			$\text{nV}/\sqrt{\text{Hz}}$	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = \emptyset\text{V}$	$f = 10 \text{ Hz}$
Noise Figure	NF		6			dB	$V_{\text{DS}} = 15\text{V}, V_{\text{GS}} = \emptyset\text{V}$ $R_G = 1 \text{M}\Omega$	$f = 10 \text{ Hz}$

TO-72 Package

Dimensions in Inches (mm)

Pin Configuration

1 Source, 2 Drain, 3 Gate, 4 Case